# MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PIFD

ESDA6V1SC6-MS

**Product specification** 





#### **Features**

- Protects up to 5 lines
- Low leakage: nA level
- Low clamping voltage
- Excellent surge protection (80W at 8/20µs)
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±20kV

Contact discharge: ±20kV

- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 18A (8/20µs)
- RoHS Compliant

#### **Mechanical Characteristics**

Package: SOT23-6

Lead Finish: Matte Tin

Case Material: "Green" Molding Compound

• UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 3 per J-STD-020

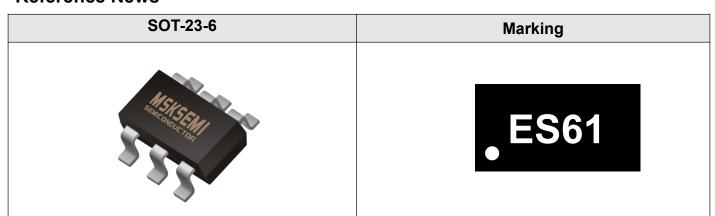
Terminal Connections: See Diagram Below

Marking Information: See Below

### **Applications**

- Audio Players
- Peripherals
- Portable Instrumentation
- Desktops PC and Servers
- Microprocessor Based Equipment
- Cell Phone Handsets and Accessories
- Notebook, Laptop, and Palmtop Computers

#### **Reference News**





## **Absolute Maximum Ratings**(Tamb=25°C unless otherwise specified)

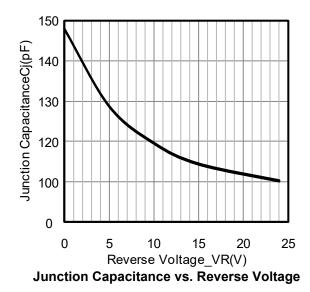
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ррр	350	W	
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	±20	Kv	
ESD per IEC 61000-4-2 (Contact)	<b>V</b> ESD	±20		
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$	
Storage Temperature Range	Тѕтл	-55 to +150	°C	

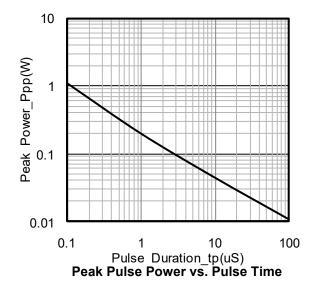
## **Electrical Characteristics**(TA=25°C unless otherwise specified)

Part Number	V <sub>RWM</sub> V <sub>BR</sub> (V)	ŀτ	<b>V</b> c	Vc		l <sub>R</sub> µ <b>A</b>	C (Pf)	
Tare realization		(V)	(mA)	@1A	(Max)	(@A)	(Max)	(Тур.)
ESDA6V1SC6-MS	5.5	6	1	15	20	18	1.0	150

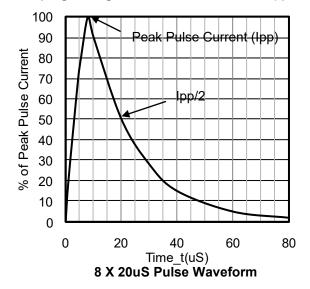


## Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)

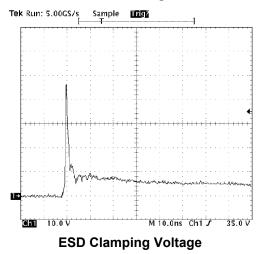




#### Clamping Voltage vs. Peak Pulse Current (tp = 8/20us)



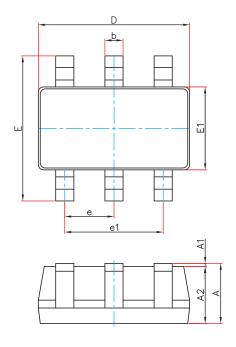
#### **Power Derating Curve**

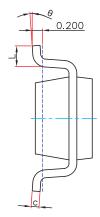


8 kV Contact per IEC61000-4-2



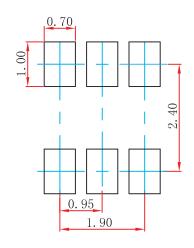
## **Package Outline Dimensions**





Symbol	Dimensions In Millimeters		Dimensions In Inches		
Syllibol	Min.	Max.	Min.	Max.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
E	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(	(BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

## **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters. 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

## **Order information**

Orderable Device	Package	Packing Option
ESDA6V1SC6-MS	SOT-23-6	3000PCS



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